TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC375AP, TC74HC375AF

4-Bit D Type Latch

The TC74HC375A is a high speed CMOS D-TYPE LATCH fabricated with silicon gate $\rm C^2MOS$ technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

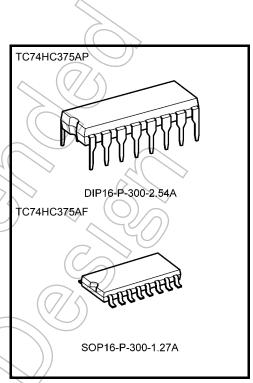
It contains two groups of 2-bit latches controlled by an enable input (G1·2 or G3·4) and each group can be used in different circuits.

Data applied to the data inputs are transferred to the Q and $\overline{Q}\,$ outputs whin the enable inputs is high. When the enable input is low, the outputs are not affected.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

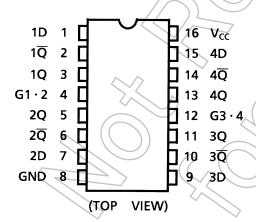
- High speed: $t_{pd} = 14 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A$ (max) at $T_{a} = 25^{\circ}C$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: | I_{OH} | = I_{OL} = 4 mA (min)
- Balanced propagation delays: t_{pLH} ≃ t_{pHI}
- Wide operating voltage range: VCC (opr) = 2 to 6 V
- Pin and function compatible with 74LS375



Weight

DIP16-P-300-2.54A : 1.00 g (typ.) SOP16-P-300-1.27A : 0.18 g (typ.)

Pin Assignment



IEC Logic Symbol

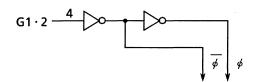
(1)		· (2)
1D -\frac{10}{20}	1D	(2) 10
G1 · 2 (4)	C1	$\frac{(2)}{(5)}$ $\stackrel{\circ}{10}$
G112 (C2	13) 20
2D (/) 3D (9)	2D	(6) 2Q (11) 2Q
3D (3)	3D	(10) 3Q
G3 · 4 (12)	C3	$\frac{(10)}{(12)}$ 3 \overline{Q}
(45)	C4	(13) 40
4D (15)	4D	(14) $4\overline{Q}$

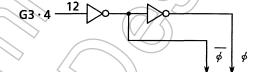
Truth Table

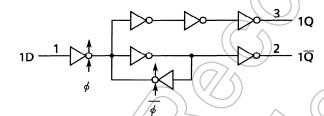
Inp	uts	Outputs		Function
D	G	Q	IQ	Function
L	Н	L	Н	_
Н	Н	Н	L	_
Χ	L	Qn	- Qn	Latch

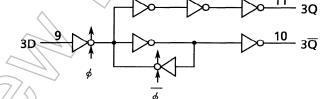
X: Don't care

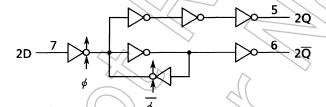
System Diagram

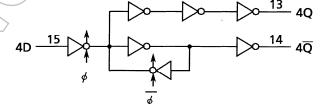












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Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	–0.5 to 7	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	−0.5 to V _{CC} + 0.5	⟨V
Input diode current	Ι _{ΙΚ}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	_ mA
Power dissipation	P _D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	VCC	2 to 6	V
Input voltage	// ŷ _{IN}	0 to V _{CC}	٧
Output voltage	Vout	0 to V _{CC}	V
Operating temperature	Topr	-40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.



Electrical Characteristics

DC Characteristics

Characteristics	acteristics Symbol Test Condition			٦	Га = 25°C		Ta = -40 to 85°C		Unit	
				V _{CC} (V)	Min	Тур.	Max	Min	Max	
				2.0	1.50	- <	1-	1.50	_	
High-level input voltage	V _{IH}		_	4.5	3.15	_		3.15	_	V
ŭ				6.0	4.20	_		4.20	_	
				2.0	_	+0	0.50	_	0.50	
Low-level input voltage	V _{IL}		_	4.5		7	1.35	_	1.35	V
				6.0	-(1	1.80	_	1.80	
	V _{OH}	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
High lavel systems			$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0		5.9	\rightarrow	V
			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	-6	4.13	> —	
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	1	5.63) —	
				2.0	_	0.0	0.1		0.1	
Lauria autaut			I _{OL} = 20 μA	4.5	_	0.0	0.1	√ —	0.1	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}		6.0	_	0.0	0.1	_	0.1	V
			I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33	
			I _{OL} = 5.2 mA	6.0		0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or	GND	6.0	_		±0.1	_	±1.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or	GND	6.0		/	4.0	_	40.0	μА

Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol Test Condition		_	Ta = 25°C		Ta = -40 to 85°C	Unit
) /	$\langle \langle \langle \langle \rangle \rangle \rangle$	V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	1		2.0	_	75	95	
Minimum pulse width	t _{W (H)}		4.5	_	15	19	ns
(G)			6.0	_	13	16	
	\wedge		2.0	_	75	95	
Minimum set-up time	ts	_	4.5	_	15	19	ns
			6.0	_	13	16	
	. (())		2.0	_	0	0	
Minimum hold time	(\therefore\)	_	4.5	_	0	0	ns
\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\			6.0	_	0	0	

AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C, input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{TLH}			4	8	no
Output transition time	t _{THL}	_		+		ns
Propagation delay time	t _{pLH}	<		14	20	
$(D-Q, \overline{Q})$	t_{pHL}	_		14	20	ns
Propagation delay time	t _{pLH}			Ma	20	
$(G-Q, \overline{Q})$	t _{pHL}	_		13	20	ns

AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Test Condition		Ta = 25°C			Ta = -40 to 85°C	
			V _{CC} (V)	Min	Typ.	Max	Min	Max	
Output transition time	tTLH tTHL	_	2.0 4.5 6.0		30 8 7	75 15 13		95 19 16	ns
Propagation delay time (D-Q, \overline{Q})	t _{pLH} t _{pHL}	-	2.0 4.5 6.0		60 17 15	120 24 20	9)	150 30 26	ns
Propagation delay time (G-Q, \overline{Q})	t _{pLH}		2.0 4.5 6,0		56 16 14	120 24 20		150 30 26	ns
Input capacitance	C _{IN}			/_)) 5	10	_	10	pF
Power dissipation capacitance	C _{PD} (Note)		\wedge		55	_		_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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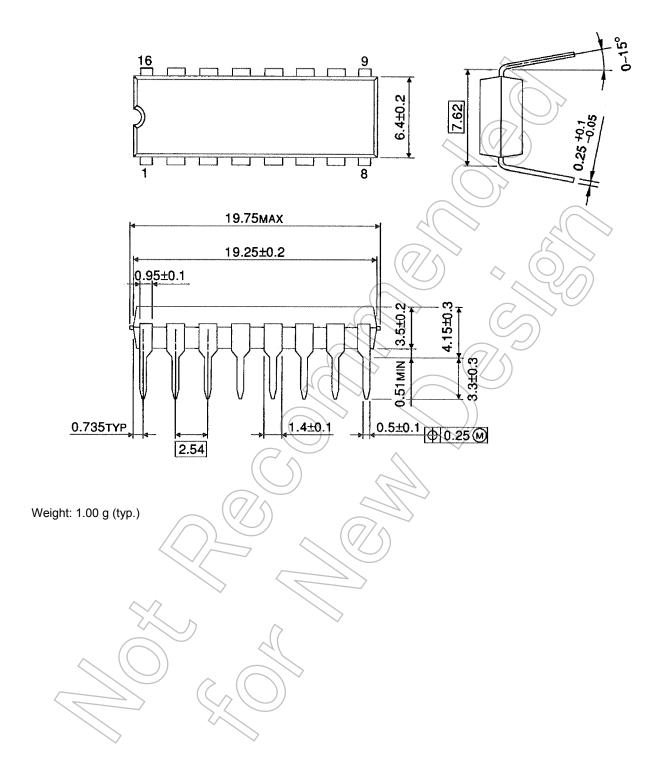
Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$ (per latch)



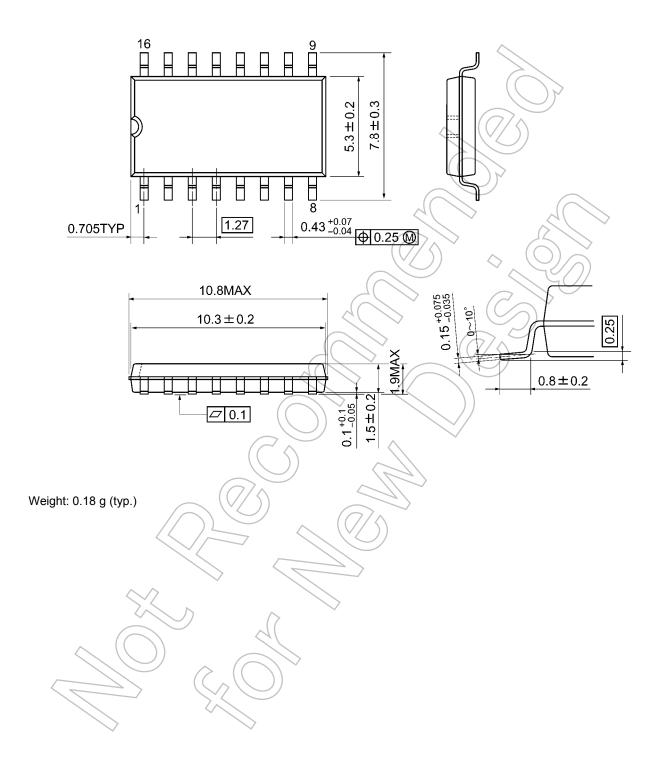
Package Dimensions

DIP16-P-300-2.54A Unit: mm



Package Dimensions

SOP16-P-300-1.27A Unit: mm



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